

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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General Purpose Transistors

NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SC-75/SOT-416 package which is designed for low power surface mount applications.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Pb-Free Packages are Available



Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	45	V
Collector-Base Voltage	V _{CBO}	50	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current – Continuous	Ic	100	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

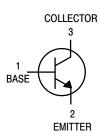
Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) T _A = 25°C	P _D	200	mW
Derated above 25°C		1.6	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) T _A = 25°C Derated above 25°C	P _D	300	mW mW/°C
Thermal Resistance, Junction–to–Ambient (Note 2)	$R_{ hetaJA}$	400	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

- 1. FR-4 @ min pad.
- 2. FR-4 @ 1.0 × 1.0 in pad.



ON Semiconductor®

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CASE 463 SC-75/SOT-416 STYLE 1

MARKING DIAGRAM



XX = Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	<u> </u>		-		•
	V _{(BR)CEO}	45	-	_	V
Collector – Emitter Breakdown Voltage $(I_C = 10 \ \mu\text{A}, \ V_{EB} = 0)$ BC847 Series	V _{(BR)CES}	50	-	_	V
Collector – Base Breakdown Voltage ($I_C = 10 \ \mu A$) BC847 Series	V _{(BR)CBO}	50	-	_	V
Emitter – Base Breakdown Voltage $(I_E=1.0~\mu\text{A}) \\ \text{BC847 Series}$	V _{(BR)EBO}	6.0	-	_	V
Collector Cutoff Current (V_{CB} = 30 V) (V_{CB} = 30 V, T_{A} = 150°C)	I _{CBO}		- -	15 5.0	nA μA
ON CHARACTERISTICS					
DC Current Gain $(I_C = 10~\mu\text{A},~V_{CE} = 5.0~\text{V}) \\ BC847A \\ BC847B \\ BC847C$	h _{FE}	- - -	90 150 270	- - -	_
$(I_{C} = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$ BC847A BC847B BC847C		110 200 420	180 290 520	220 450 800	
Collector – Emitter Saturation Voltage ($I_C = 10$ mA, $I_B = 0.5$ mA) ($I_C = 100$ mA, $I_B = 5.0$ mA)	V _{CE(sat)}	-	- -	0.25 0.6	V
Base – Emitter Saturation Voltage ($I_C = 10$ mA, $I_B = 0.5$ mA) ($I_C = 100$ mA, $I_B = 5.0$ mA)	V _{BE(sat)}	<u> </u>	0.7 0.9	_ _	V
Base – Emitter Voltage (I_C = 2.0 mA, V_{CE} = 5.0 V) (I_C = 10 mA, V_{CE} = 5.0 V)	V _{BE(on)}	580 -	660 -	700 770	mV
SMALL-SIGNAL CHARACTERISTICS	•		•		•
Current – Gain – Bandwidth Product ($I_C = 10$ mA, $V_{CE} = 5.0$ Vdc, $f = 100$ MHz)	f _T	100	-	_	MHz
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	C _{obo}	-	-	4.5	pF
Noise Figure (I _C = 0.2 mA, V_{CE} = 5.0 Vdc, R_S = 2.0 k Ω , f = 1.0 kHz, BW = 200 Hz)	NF	-	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

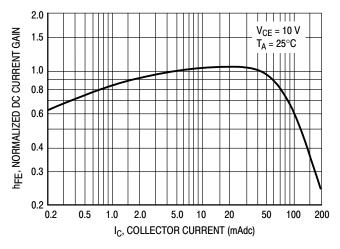


Figure 1. Normalized DC Current Gain

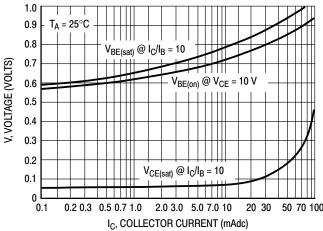


Figure 2. "Saturation" and "On" Voltages

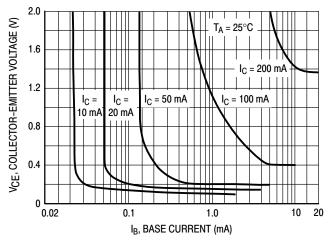


Figure 3. Collector Saturation Region

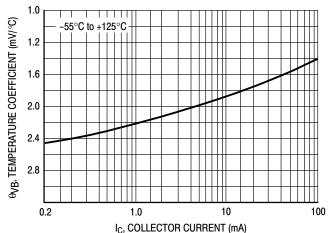


Figure 4. Base-Emitter Temperature Coefficient

BC847

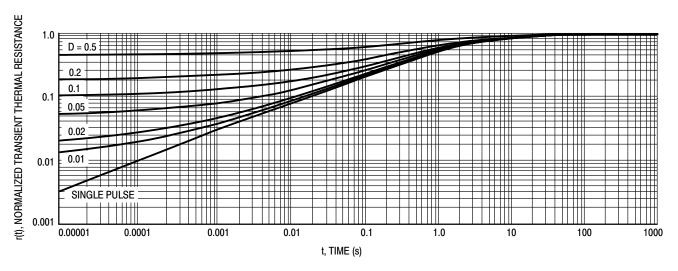


Figure 5. Normalized Thermal Response

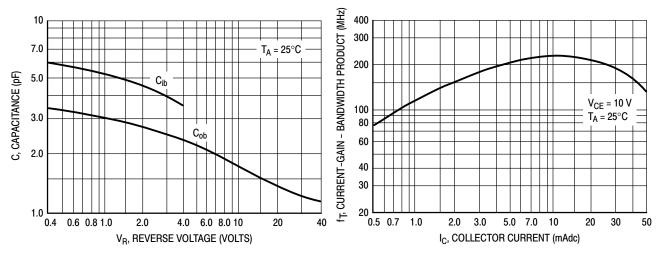


Figure 6. Capacitances

Figure 7. Current-Gain - Bandwidth Product

ORDERING INFORMATION

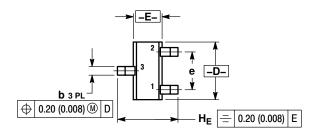
Device	Marking	Package	Shipping [†]
BC847ATT1	1E	SC-75/SOT-416	3,000 / Tape & Reel
BC847BTT1	1F	SC-75/SOT-416	
BC847BTT1G	1F	SC-75/SOT-416 (Pb-Free)	3,000 / Tape & Reel
NSVBC847BTT1G*	1F	SC-75/SOT-416 (Pb-Free)	3,000 / Tape & Reel
BC847CTT1G	1G	SC-75/SOT-416 (Pb-Free)	3,000 / Tape & Reel

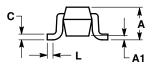
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable.

PACKAGE DIMENSIONS

SC-75/SOT-416 CASE 463 ISSUE F





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.

	NALL	LINACTO	-DC	INCHES		
	MILLIMETERS					
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
E	0.70	0.80	0.90	0.027	0.031	0.035
е	1.00 BSC			C	.04 BSC	
L	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.061	0.063	0.065

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